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Cation–anion substitution induced spectral tuning and thermal stability optimization in Sr₂SiO₄:Eu phosphors†

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Spectral tuning and thermal stability are important for the optimization and modification of phosphor materials. Herein we report a solid solution of Sr₂Si_{1-x}Al_xO_{4-2x}N_x:Eu phosphors in which cation–anion substitution (Al³⁺–N³⁻ replacing Si⁴⁺–O²⁻) leads to the co-existence of Eu²⁺ and Eu³⁺ activators even under a reducing atmosphere. X-ray diffraction, FT-IR, photoluminescence analysis, UV-vis absorption and fluorescence lifetime studies indicated that the structure reconstruction contributes to tunable emission colors and better thermal quenching behavior, which are valuable for pc-WLED applications.

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1 Introduction

Due to its high energy efficiency, long lifetime, short response time, huge energy savings and environmental friendliness, nowadays phosphor-converted white light-emitting diodes (pc-WLEDs) have gained a broad consensus to act as the next-generation solid state lighting (SSL) source after incandescent and fluorescent lamps. This profound achievement benefits from continual research of technologies and materials related to LEDs, which show great prospects in visual signals, common lighting, communication, sensors, light matter interactions and so on.^{1–3} At present, a typical pc-WLED is assembled through a blue InGaN LED chip and a yellow cerium(III)-doped yttrium aluminium garnet (YAG:Ce³⁺) phosphor. However, with long-wavelength spectral emission lacked, this solution to generate white light suffers from a high correlated color temperature (CCT > 4000 K) and a poor color rendering index (CRI < 80). To improve the CRI and tune the CCT value, LED chips (blue-emitting or n-UV) coated with red-, yellow-/green- and blue-emitting multi-phased phosphors have attracted considerable attentions. But this multi-phased phosphors method frequently results in increasing manufacture cost, and strong reabsorption owing to spectral mismatch.^{4,5} Plainly, the phosphors play a key role in producing high-quality white lighting. Therefore, in addition to luminescence efficiency and chemical/thermal stability, spectral tuning and matching must be considered for light-conversion luminescent materials in WLEDs.

Given the unavoidably spectral mismatching problem of multi-phased phosphor solution, the realization of multi-color luminescence in a single phase offers a promising possibility to generate white light with superior CRI and lower CCT, which also reconcile spectra adjustment and energy loss simultaneously. The most common and easiest way for multi-color emitting is the combination of several luminescence centers in one host, like Eu²⁺/Mn²⁺ codoping phosphors.^{6,7} However, this multi-color luminescence depends on the energy transfer from sensitizer to activator in the co-doping system, implying the relatively low luminescence efficiency.

Recently, the focus on the tunable luminescence of phosphors has become a research hotspot, especially based on the modification of local crystal structure including doping level control, cation substitution, anion substitution and cation–anion substitution *etc.*^{8–10} For instance, Sato *et al.* realized the tailoring of deep-red luminescence in Ca₂SiO₄:Eu²⁺ on the basis of the Eu²⁺ ions tending to occupy another cation site (corresponding to long-wavelength emitting) with the increasing doping level.¹¹ Xia described the strategy of “chemical unit cosubstitution” to tune luminescent properties in Ca₂(Al_{1-x}Mg_x)(Al_{1-x}Si_{1+x})O₇:Eu²⁺ and Lu₃(Al,Mg)₂(Al,Si)₃O₁₂:Ce³⁺ with the substitution of Al³⁺–Al³⁺ couple by Mg²⁺–Si⁴⁺ pair.^{12,13} Generally, all these variations in host composition usually alter the symmetry, coordination environment, crystal field strength, covalence, and the energy transfer, thus influencing luminescence properties. In particular, the approach of cation–anion substitution can result in tunable valences of the activators in some special cases, for example, Huang *et al.* reported a tunable valence of Eu in Ca₁₂Al₁₄O₃₂F₂ by controlling the activator sites through the replacement of Si–O by Al–F.¹⁴ Xia *et al.* also achieved coexistence of Eu²⁺ and Eu³⁺ ions in the Ca_{2+x}La_{8-x}(SiO₄)_{6-x}(PO₄)_xO₂ host lattice *via* the preferential site occupancy and charge balance of cation co-substitution.¹⁵ This

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creative discovery, obtaining the emissions of Eu^{2+} and Eu^{3+} ions in a single phase simultaneously, performs great benefits in pc-WLEDs due to their abundant emission colors of 5d–4f or 4f–4f transitions. Though the cation–anion substitution method gets the natural advantage to obtain white light emitting in pc-WLEDs with superior CRI and lower CCT, published literatures and alternative hosts are relative few until now. On the other hand, this approach commonly needs a high level of doping or substitution, which easily sacrifices the emission intensity and thermal stability of phosphor.^{9,14,16}

$(\text{Ca},\text{Sr},\text{Ba})_2\text{SiO}_4:\text{Eu}^{2+}$ is a widely used class of phosphor with interesting thermal quenching behavior. These compounds exhibit efficient excitation under near-UV and blue light, with emissions ranging from green for $\text{Ba}_2\text{SiO}_4:\text{Eu}^{2+}$ to yellow for $\text{Sr}_2\text{SiO}_4:\text{Eu}^{2+}$.^{17–19} The cation substitution (e.g., $(\text{Ca}/\text{Sr}/\text{Ba})_2\text{SiO}_4:\text{Eu}^{2+}$) and anion substitution (e.g., $\alpha'\text{-Sr}_2\text{Si}_{3x/4}\text{O}_{2-x}\text{N}_x:\text{Eu}^{2+}$, $\text{Sr}_2\text{SiN}_z\text{O}_{4-1.5z}:\text{Eu}^{2+}$ and $\text{Sr}_2\text{Si}(\text{O}_{1-x}\text{N}_x)_4:\text{Eu}^{2+}$) performed to optimize the emission peak and thermal stability.^{20–23} However, no report about the effects of cation–anion cosubstitution on the luminescence property in $\text{Sr}_2\text{SiO}_4:\text{Eu}^{2+}$ has been previously noted in the literature. In this study, the cation–anion cosubstitution of $\text{Si}^{4+}\text{-O}^{2-}$ by $\text{Al}^{3+}\text{-N}^{3-}$ in $\text{Sr}_2\text{SiO}_4:\text{Eu}^{2+}$ was investigated in detail, including the variation of structure and luminescence property. The disordered solid-solution $\text{Sr}_2\text{Si}_{1-x}\text{Al}_x\text{O}_{4-2x}\text{N}_x:\text{Eu}$ resulted in the mixed Eu valences, continuous spectral tuning and thermal stability optimization, which are valuable for high-quality pc-WLEDs applications.

2 Experimental section

2.1 Materials and synthesis

$\text{Sr}_{1.98}\text{Si}_{1-x}\text{Al}_x\text{O}_{4-2x}\text{N}_x:0.02\text{Eu}$ phosphors were prepared from appropriate stoichiometric mixture of SrCO_3 (A. R.), SiO_2 (A. R.), AlN (A. R.), and Eu_2O_3 (A. R.) by traditional high temperature solid-state reaction method. All raw materials were purchased commercially without further treatment. In a typical process, the starting materials were weighted and mixed thoroughly in an agate mortar according to different values of x . Then the powder mixtures were annealed at 1250 °C for 4 h in a corundum crucible under the reducing atmosphere ($\text{N}_2/\text{H}_2 = 95:5\%$). The as-prepared samples were cooled to room temperature naturally, and after discarding the top layer of the nongrinded products, the interior of uniform samples was ground into powder for next characterization. For comparison, sample $\text{Sr}_{1.98}\text{SiO}_4:0.02\text{Eu}^{3+}$, synthesized in air was also obtained under same sintered procedure.

2.2 Characterization

Crystal structure of the samples was analyzed by X-ray powder diffractometer (SHIMADZU, XRD-6000, Cu K α radiation, $\lambda = 0.15406$ Å). The data were collected in a 2θ range from 20° to 80° with a scanning step of 0.02° and a scanning rate of 4° min⁻¹. Room-temperature photoluminescence and photoluminescence excitation (PLE) spectra were measured with a Hitachi F-7000 (Tokyo, Japan) spectrophotometer equipped with a 150 W xenon arc lamp. The digital pictures of the samples are

photographed using a digital camera (Canon EOS 40D, Tokyo, Japan). Temperature-dependent (300–460 K) photoluminescence spectra were conducted using a heating apparatus (OXFORD instrument, Oxon, UK) in combination with the above Hitachi 7000 spectrophotometer. Decay curves were measured using a FSP920 Time Resolved and Steady State Fluorescence Spectrometers (Edinburgh Instruments) equipped with a 450 W Xe lamp, a 150 W nF900 flash lamp, TM300 excitation monochromator and double TM300 emission monochromators and thermo-electric cooled red-sensitive PMT. Fourier-transform infrared (FT-IR) spectra were measured on a BRUKER TENSOR 27 spectrophotometer in the range of 400–4000 cm⁻¹ using the KBr pellet (~2 wt%) method. UV-vis spectra were measured on a Shimadzu UV-2550 spectrophotometer.

3 Results and discussion

The phase purities of the $\text{Sr}_{1.98}\text{Si}_{1-x}\text{Al}_x\text{O}_{4-2x}\text{N}_x:0.02\text{Eu}$ ($x = 0\text{--}0.1$) compounds were confirmed using X-ray powder diffraction (XRD), as shown in Fig. 1. Sr_2SiO_4 has two crystallographic phases: the high temperature $\alpha'\text{-Sr}_2\text{SiO}_4$ (orthorhombic, $Pmab$) phase and the low temperature $\beta\text{-Sr}_2\text{SiO}_4$ (monoclinic, $P2_1/c$) phase. The low temperature (~358 K) of $\alpha' \leftrightarrow \beta$ phase transition results in frequently co-existence of the two phases through a short-range rearrangement of the coordination structure without breaking any bonds.^{24,25} When sintered at 1250 °C, it shows that all the diffraction peaks matched well with the $\alpha'\text{-Sr}_2\text{SiO}_4$ phase, except for small amounts impurity of $\beta\text{-Sr}_2\text{SiO}_4$ phase (marked as β symbol) peaking at 27.6° and 32.3° (2θ) with x values of 0 and 0.01. These suggest that the introduction of europium and AlN cannot affect the main crystal structure through partial replacement. After the incorporation of AlN into Sr_2SiO_4 host, the diffraction peaks also show small shifts toward larger 2θ value, indicating the formation of solid solutions. When x value exceeds 0.1, unknown phases were detected and the crystallinity degree of the obtained production was lower, as signposted in Fig. S1 in ESI.† The FT-IR spectra of $\text{Sr}_{1.98}\text{Si}_{1-x}\text{Al}_x\text{O}_{4-2x}\text{N}_x:0.02\text{Eu}$ ($x = 0$ and 0.1) phosphors also support the

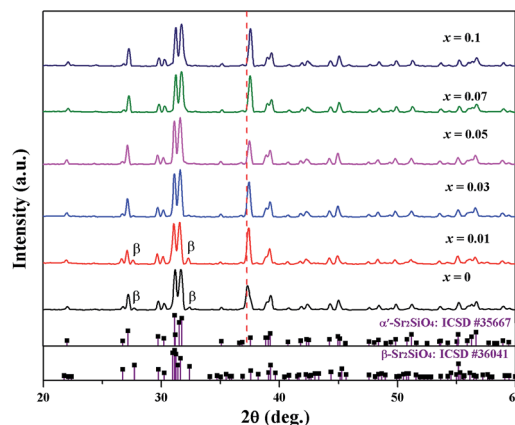


Fig. 1 XRD patterns of $\text{Sr}_{1.98}\text{Si}_{1-x}\text{Al}_x\text{O}_{4-2x}\text{N}_x:0.02\text{Eu}$ ($x = 0\text{--}0.1$), together with the standard data for $\alpha'/\beta\text{-Sr}_2\text{SiO}_4$ (ICSD #35667 and ICSD #36041) as reference.



successful incorporation of AlN into host compounds, in which the peak of Sr/Eu–N bond vibration appears in sample of $x = 0.1$, while the sample with $x = 0$ does not show such peak (see Fig. S2 in ESI†).

Both in α' -Sr₂SiO₄ and β -Sr₂SiO₄, Sr²⁺ ion occupies two kind of inequivalent sites: the ten-coordinated Sr(1) and the nine-coordinated Sr(2) sites, while Sr(1) and Sr(2) occur in the same amount. Given the change of O atom position and occupation, the α' -Sr₂SiO₄ phase further exist disordered (isotropic) and ordered (anisotropic) structure models.²¹ In the disordered α' -Sr₂SiO₄, each atom lying on the mirror plane was split into two, in very close positions equivalent by symmetry; and four kind of oxygen atoms can be observed, as shown in Fig. 2. After careful analysis the cases Sr₂SiN₂O_{4-1.5z}:Eu²⁺ and Sr₂Si(O_{1-x}N_x)₄:Eu²⁺, it is not hard to find that the obtained Sr_{1.98}Si_{1-x}Al_xO_{4-2x}N_x:0.02Eu ($x = 0-0.1$) phosphors also possess the disordered α' -Sr₂SiO₄ phase in consideration of the inhomogeneous substitutions (Al³⁺-N³⁻ → Si⁴⁺-O²⁻), resulting in local coordination environment changes.

Fig. 3 gives the excitation and emission spectra of samples Sr₂Si_{1-x}Al_xO_{4-2x}N_x:0.02Eu ($x = 0, 0.07$ and 0.1). As seen in Fig. 3a, the emission spectrum of Sr_{1.98}Si_{1-x}Al_xO_{4-2x}N_x:0.02Eu ($x = 0$), namely, Sr_{1.98}SiO₄:0.02Eu²⁺, reveals two obviously broad emission bands under 320 nm excitation. Due to the similar ion radii of Sr²⁺ (1.31 Å, 9CN; 1.36 Å, 10CN) and Eu²⁺ (1.30 Å, 9CN; 1.35 Å, 10CN), the doped Eu²⁺ ions will occupy the Sr²⁺ sites in Sr₂SiO₄ host lattice.²⁶ Eu(1) and Eu(2) emissions, originating

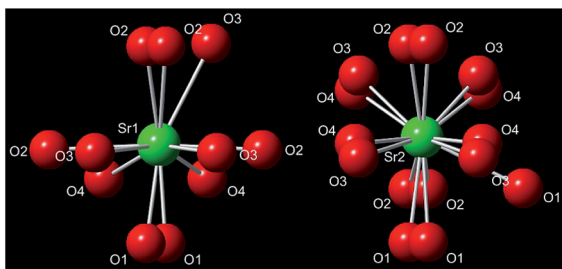


Fig. 2 Coordination spheres of the two different Sr²⁺ sites in the disordered α' -Sr₂Si_{1-x}Al_xO_{4-2x}N_x.

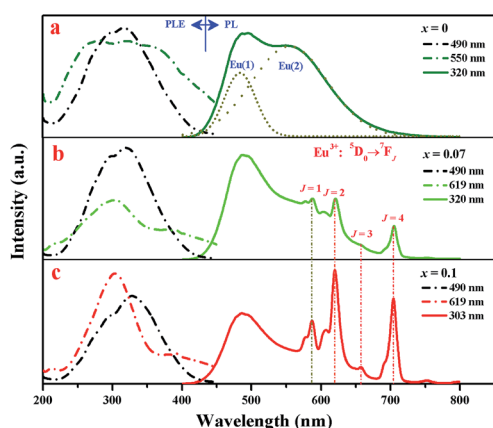


Fig. 3 Room-temperature PLE and PL spectra of Sr_{1.98}Si_{1-x}Al_xO_{4-2x}N_x:0.02Eu ($x = 0, 0.07$ and 0.1) phosphors.

from the Eu²⁺ ions incorporation at Sr(1) and Sr(2) sites respectively, are seriously affected by local crystal field. Accordingly, the broad emission bands can be fitted to two subbands centered at 490 nm and 550 nm by using Gaussian functions, related to the parity allowed 4f⁶5d → 4f⁷ transitions of Eu²⁺ ions. The higher-energy emission peak (490 nm) corresponds to the Eu(1) emission owing to its loose environment (10-coordination), while the lower-energy emission peak (550 nm) originates from Eu(2) emission for the tighter environment (9-coordination).²⁷ On the other hand, the excitation spectrum ($\lambda_{em} = 550$ nm) of Sr_{1.98}SiO₄:0.02Eu²⁺ shows a broad band ranging from 250 nm to 450 nm, which is attributable to the 4f⁶5d multiplets of Eu²⁺ excited states. However, the excitation spectrum ($\lambda_{em} = 490$ nm) exhibits a narrower excitation band centered at 320 nm.

The introduction of AlN into Sr₂SiO₄:Eu was supposed to replace Si⁴⁺-O²⁻, resulting in Sr₂Si_{1-x}Al_xO_{4-2x}N_x:0.02Eu phosphors under the reducing atmosphere. Note that sharp red emission appeared as the doping amount of cation-anion substitution exceeds 0.07 (see in Fig. 3b and c). Furthermore, with doping content level of AlN increases, the sharp red emission intensity increases while the luminescence (~490 nm) originating from Eu²⁺ decreases to intuitively disappearing at $x = 0.5$, as shown in Fig. 4a. Given the well-known characteristic 4f–4f electron transitions of Eu³⁺, we concluded these sharp emissions comes from Eu³⁺ emission, which means that two activators of Eu³⁺ and Eu²⁺ co-exists in Sr₂Si_{1-x}Al_xO_{4-2x}N_x:0.02Eu phosphors ($0.07 \leq x < 0.5$). To confirm this, sample Sr_{1.98}SiO₄:0.02Eu³⁺ was synthesized in air, and its PL and PLE spectra were given in Fig. S3 in ESI.† The strongest line emission peak at 614 nm (⁵D₀ → ⁷F₂) and other characteristic peaks are consistent with the sharp red emissions in Sr_{1.98}Si_{1-x}Al_xO_{4-2x}N_x:0.02Eu. However, obvious difference occurs between

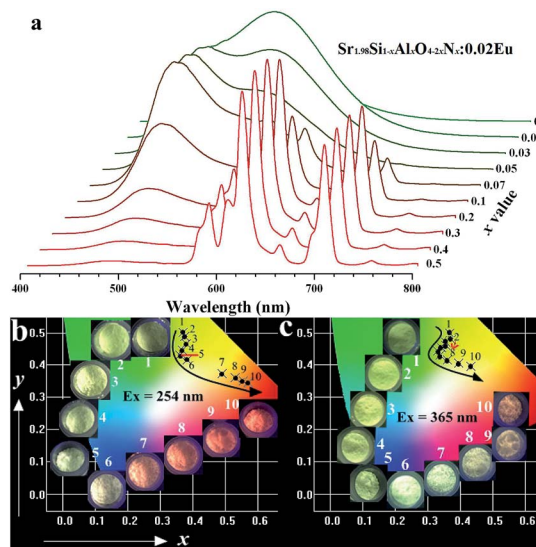


Fig. 4 (a) PL spectra ($\lambda_{ex} = 320$ nm) of Sr_{1.98}Si_{1-x}Al_xO_{4-2x}N_x:0.02Eu ($x = 0-0.5$). (b & c) Dependence of CIE chromaticity coordinates and digital photos on various x values upon 254 and 365 nm excitation, respectively. The numbers 1–10 corresponds to the x values from 0 to 0.5.



the charge transfer bands (CTB) of $O^{2-} \rightarrow Eu$: the CTBs of $Sr_{1.98}SiO_4:0.02Eu^{3+}$ and $Sr_{1.98}Si_{1-x}Al_xO_{4-2x}N_x:0.02Eu$ phosphors locate at 254 nm and 303 nm respectively, indicating the different band transitions and successful reconstruction through cation-anion substitution in host lattices. Besides, Fig. S4† shows the UV-vis absorption spectra of $Sr_2Si_{1-x}Al_xO_{4-2x}N_x:0.02Eu$ ($x = 0$ and 0.1) phosphors. A strong absorption band in the range 200–320 nm of sample $x = 0.1$ was mainly ascribed to the intra configurational 4f–4f transition from the ground $4F_0$ level of Eu^{3+} , while the broad band in the range 250–500 nm of sample $x = 0$ are contributed to the 5d–4f transitions of Eu^{2+} , which corresponds to corresponding excitation spectra. These results are in good agreement with those reported in the literature.²⁸ Fig. 4b further lists the photographs and Commission International de l'Eclairage (CIE) coordinates of all samples ($x = 0$ – 0.5). As shown, the luminescence colors can be tuned from green to red, corresponding CIE coordinates of these samples are regularly shifted from (0.38, 0.465) to (0.569, 0.346), (0.368, 0.498) to (0.432, 0.396) under 254 nm and 365 nm excitation respectively.

Fig. 5 depicts the normalized lifetime decay curves for samples $Sr_2Si_{1-x}Al_xO_{4-2x}N_x:0.02Eu$ ($x = 0$ and 0.1) by monitoring at 619 nm and 490 nm under 320 nm excitation. It turns out that the decay curve ($x = 0$, $\lambda_{em} = 619$ nm; $x = 0.1$, $\lambda_{em} = 490$ nm) can be well fitted by a second order exponential equation:

$$I(t) = I_0 + A_1 \exp(-t/\tau_1) + A_2 \exp(-t/\tau_2)$$

While the decay curve ($x = 0.1$, $\lambda_{em} = 619$ nm) can be well fitted by the nonexponential equation:^{29,30}

$$\tau = \int_0^{\infty} I(t)dt / \int_0^{\infty} I(t)dt$$

where $I(t)$ represents the luminescent intensity at time t , A_1 and A_2 are constants while τ_1 and τ_2 are the decay times for the exponential components. These results further confirm the structure reconstruction and the coexistence of Eu^{2+} and Eu^{3+} activators after AlN incorporation. With the combination of crystal sites and the characteristic emissions of Eu^{2+} and Eu^{3+} ions, the double exponential components τ_1 and τ_2 corresponds to the lifetime of two $Eu(1)^{2+}$ and $Eu(2)^{2+}$ emissions, and the

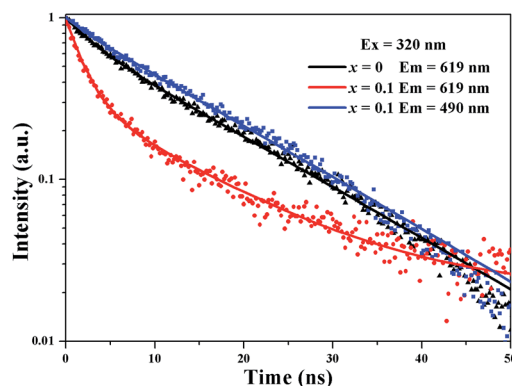


Fig. 5 Decay curves of $Sr_{1.98}Si_{1-x}Al_xO_{4-2x}N_x:0.02Eu$ ($x = 0$ and 0.1), the solid line was obtained by fitting.

lifetime τ ($x = 0.1$, $\lambda_{em} = 619$ nm) reflects the comprehensive results of Eu^{3+} and Eu^{2+} emissions. The average lifetimes for above decay curves were calculated to be 13.40 ns, 10.21 ns and 13.66 ns, respectively.

From the point view of applied physics, multiple factors, such as coordination environment, crystal site size and band gap of the compound, are the reasons for valance stability of lanthanide. Partial substitution commonly results in the variations of local crystal structure. Based on the ions radius: $r(Si^{4+}) = 0.26 \text{ \AA}$ (4CN), $r(Al^{3+}) = 0.39 \text{ \AA}$ (4CN), $r(N^{3-}) = 1.46 \text{ \AA}$ (4CN) and $r(O^{2-}) = 1.38 \text{ \AA}$ (4CN),²⁶ the cation-anion substitution of $Si^{4+}-O^{2-}$ by $Al^{3+}-O^{3-}$ leads to the expansion of $(Si/Al)(O/N)_4$ tetrahedron, which will shrink the position of Sr^{2+} sites. Fig. S4† shows the excitation spectra ($\lambda_{em} = 490$ nm) of samples $Sr_{1.98}Si_{1-x}Al_xO_{4-2x}N_x:0.02Eu$ ($x = 0$ – 0.2). The strongest excitation band trends to redshift from 318 nm to 350 nm with increasing x value, which results from the suppress of Eu^{2+} vibration after cation-anion substitution. In the cases of $Ca_{12}Al_{14-2}Si_2O_{32}F_{2-z}:Eu$, and $Ca_{1+x}Y_{1-x}Al_{1-x}Si_xO_4:Eu$, the occupation sites of Eu^{3+} in CaO_6F and CaO_9 get to expand after corresponding substitutions, which could favor the reduction Eu^{3+} to Eu^{2+} .^{14,31} On the contrary, the shrinkage of $(Sr/Eu)O_9$ in $Sr_2Si_{1-x}Al_xO_{4-2x}N_x:Eu$ gets the ability to fix the activators as trivalent valence.³² Therefore, here the cation-anion substitution contributes to the emerge of Eu^{3+} in $Sr_2Si_{1-x}Al_xO_{4-2x}N_x:Eu$ even under the reducing atmosphere.

It is vulnerable to overlook the fact that the activator Eu^{3+} emerges at Sr(2) site initially, not just because the peak position of Eu^{3+} emission locates at the longer-wavelength side. Careful analysis was conducted below. As mentioned before, there are no obvious sharp emissions of Eu^{3+} activator in the emission spectra of samples $0 \leq x \leq 0.05$ (see Fig. 4a). Specifically, the emission intensity of Eu^{2+} at Sr(2) site decreases with the doping content of AlN increases, but the emission intensity of Eu^{2+} at Sr(1) site increases in the range of $0 \leq x \leq 0.07$. On the other hand, the Eu^{3+} ions have smaller ion radius than that of Eu^{2+} ions, indicating that Eu^{3+} prefer to occupy at the compact site. Fig. 6 further represents the emission spectra fitted with two

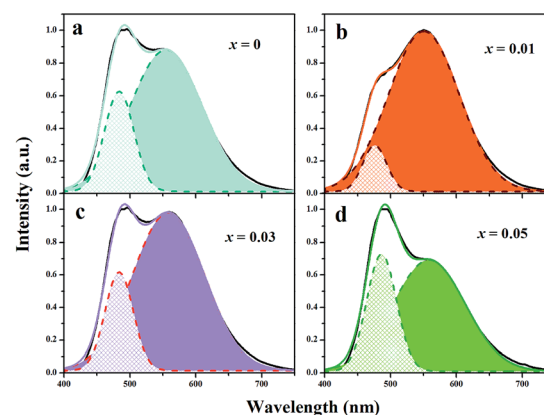


Fig. 6 Emission spectra fit to two Gaussian functions show the contribution to the emission spectra from Eu^{2+} in two distinct crystallographic sites. Dashed lines represent the individual Gaussian functions and the solid line represents the total fit.



Gaussian functions of samples $\text{Sr}_2\text{Si}_{1-x}\text{Al}_x\text{O}_{4-2x}\text{N}_x:0.02\text{Eu}$ ($x = 0, 0.01, 0.03$ and 0.05), which shows the contribution of Eu(1) and Eu(2) emissions in two distinct crystallographic sites to the total emission spectra. The proportion of Eu(1) emission to total emission varies from 25.2%, 12.2%, 11.2% to 16.2% with x values of 0, 0.01, 0.03 and 0.05, respectively, which that of Eu(2) emissions are 79.2%, 91.4%, 40.9% and 35.6%. The results show that the integrated area of Eu(2) emission to total emission increase when x value rises from 0 to 0.01. This may contribute to the energy transfer between Eu^{2+} ions at Sr sites because the large band overlap of excitation spectrum of Eu^{2+} in Sr(2) site and emission spectrum of Eu^{2+} in Sr(1) site. When x value exceeds 0.03, the proportion of Eu(1) emission increases due to part of Eu activators at Sr(2) site fixing as Eu^{3+} ions with the amount of cation-anion substitution increases.

For applications in high power LEDs, the thermal stability of phosphors must be taken into consideration due to high operating temperature. Fig. 7 gives the temperature-dependent emission spectra of $\text{Sr}_{1.98}\text{Si}_{1-x}\text{Al}_x\text{O}_{4-2x}\text{N}_x:0.02\text{Eu}$ ($x = 0, 0.07$ and 0.1), plotted in a two-dimensional wavelength-temperature contour map. For all emissions at different temperatures (300–460 K), the 5d–4f transitions of Eu^{2+} at Sr(1) site ($x = 0, 0.07$ and 0.1) show the same peak positions at 490 nm, while the emission of Eu^{2+} in Sr(2) site ($x = 0$) exhibit strong temperature quenching. Of course, the contour map also shows obvious emission of Eu^{3+} ions. With respect to the integrated PL intensity at different temperature, detail information was represented in Fig. 7d. As seen, the PL intensity shows a constant decreasing with the temperature increasing from 300 K to 460 K due to the nonradiative energy transfer. The decreasing integrated PL intensity can be well fitted by Arrhenius equation³³

$$I(T) = I_0 / (1 + C \exp(-E_A/kT))$$

where I_0 and $I(T)$ are the intensity at temperature T , respectively. k is the Boltzmann constant while C is a rate constant for the

thermally activated escape. E_A is the activation energy for the thermal quenching process. Thus, the corresponding E_A of $\text{Sr}_{1.98}\text{Si}_{1-x}\text{Al}_x\text{O}_{4-2x}\text{N}_x:0.02\text{Eu}$ ($x = 0, 0.03, 0.05, 0.07, 0.1$ and 0.2) are calculated to be 0.25 eV, 0.46 eV, 0.43 eV, 0.35 eV, 0.40 eV and 0.42 eV, respectively. Compared to sample $\text{Sr}_{1.98}\text{SiO}_4:0.02\text{Eu}^{2+}$ ($x = 0$), the thermal quenching optimization was attributed to two factors, partly for the incorporation of nitrogen into the host and partly because the emission of Eu(2) possessing poor thermal stability tends to disappear with cation-anion substitution.

4 Conclusions

The $\text{Sr}_2\text{Si}_{1-x}\text{Al}_x\text{O}_{4-2x}\text{N}_x:\text{Eu}$ ($0 \leq x \leq 0.5$) phosphors were prepared by a conventional solid state reaction method. The XRD analysis results indicated that cation-anion substitution of $\text{Si}^{4+}-\text{O}^{2-}$ by $\text{Al}^{3+}-\text{N}^{3-}$ incorporated into α' - Sr_2SiO_4 successfully and form substitutional solid solution. The replacement could achieve the co-existence of Eu^{2+} and Eu^{3+} activators. While the Eu^{3+} ions preferred to occupy at the Sr(2) site and its characteristic emissions emerged around a doping content level of 0.07. The $\text{Sr}_2\text{Si}_{1-x}\text{Al}_x\text{O}_{4-2x}\text{N}_x:\text{Eu}$ phosphor exhibited broad excitation bands and both green emission (~ 490 nm and ~ 550 nm) and red emission (~ 619 nm), corresponding luminescence colors can be tuned from green to red with CIE coordinates shifting from (0.38, 0.465) to (0.569, 0.346), (0.368, 0.498) to (0.432, 0.396) under 254 nm and 365 nm excitation respectively. Furthermore, the cation-anion substitution could improve the thermal stability of the $\text{Sr}_2\text{SiO}_4:\text{Eu}^{2+}$ phosphor. Based on the adjustable emission properties from green to red and the optimized thermal stability, $\text{Sr}_2\text{Si}_{1-x}\text{Al}_x\text{O}_{4-2x}\text{N}_x:\text{Eu}$ phosphor could be a good candidate for use in white light emitting diodes.

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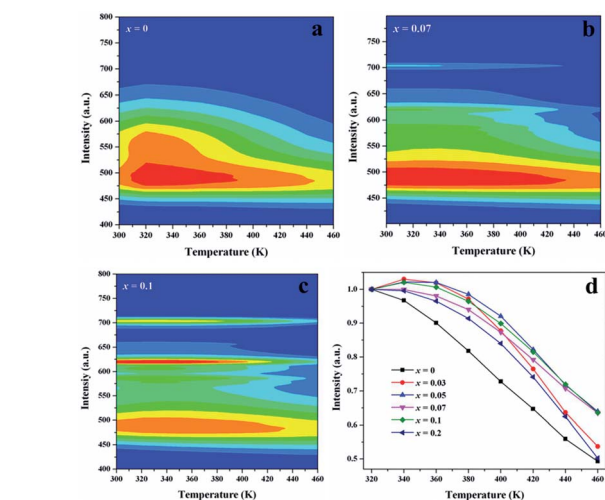


Fig. 7 (a–c) Temperature-dependent (300–460 K) PL spectra contour plots for $\text{Sr}_{1.98}\text{Si}_{1-x}\text{Al}_x\text{O}_{4-2x}\text{N}_x:0.02\text{Eu}$ ($x = 0, 0.07$ and 0.1) excited at 320 nm; (d) dependence of integrated PL intensities on measured temperature for samples $\text{Sr}_2\text{Si}_{1-x}\text{Al}_x\text{O}_{4-2x}\text{N}_x:0.02\text{Eu}$ ($x = 0-0.2$).



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